

International Rectifier



**MBRD650CT
MBRD660CT**

SCHOTTKY RECTIFIER

6 Amp



D-Pak (TO-252AA)

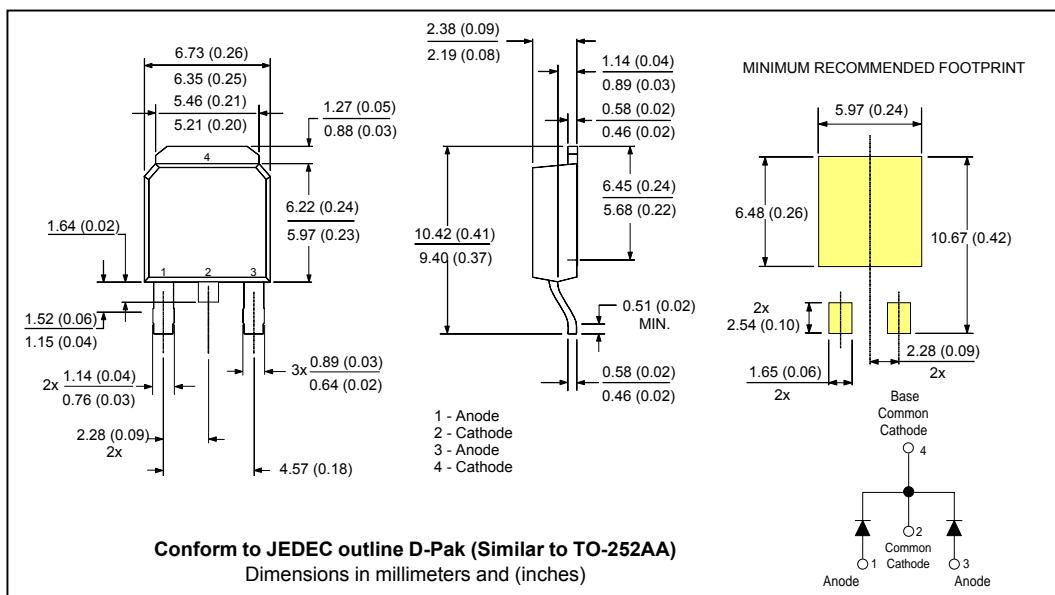
Major Ratings and Characteristics

Characteristics	MBRD650CT MBRD660CT	Units
$I_{F(AV)}$ Rectangular waveform	6	A
V_{RRM}	50-60	V
I_{FSM} @ $t_p=5\mu s$ sine	490	A
V_F @ 3Apk, $T_J = 125^\circ C$ (per leg)	0.65	V
T_J range	-40 to 150	°C

Description/Features

The MBRD650CT, MBRD660CT surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Popular D-PAK outline
- Center tap configuration
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



Voltage Ratings

Part number	MBRD650CT	MBRD660CT
V_R Max. DC Reverse Voltage (V)	50	60
V_{RWM} Max. Working Peak Reverse Voltage (V)		

Absolute Maximum Ratings

Parameters	Value	Units	Conditions		
$I_{F(AV)}$ Max. Average Forward (Per Leg) Current * See Fig. 5 (Per Device)	3.0 6	A	50% duty cycle @ $T_J = 128^\circ\text{C}$, rectangular wave form		
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 7	490	A	5μs Sine or 3μs Rect. pulse	Following any rated load condition and with rated V_{RRM} applied	
	75		10ms Sine or 6ms Rect. pulse		
E_{AS} Non-Repet. Aval. Energy (Per Leg)	6	mJ	$T_J = 25^\circ\text{C}$, $I_{AS} = 1$ Amps, $L = 10$ mH		
I_{AR} Repetitive Avalanche Current (Per Leg)	0.6	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical		

Electrical Specifications

Parameters	Value	Units	Conditions	
V_{FM} Max. Forward Voltage Drop (Per Leg) * See Fig. 1 (1)	0.7	V	@ 3A	$T_J = 25^\circ\text{C}$
	0.9	V	@ 6A	
	0.65	V	@ 3A	$T_J = 125^\circ\text{C}$
	0.85	V	@ 6A	
I_{RM} Max. Reverse Leakage Current (Per Leg) * See Fig. 2 (1)	0.1 15	mA	$T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	$V_R = \text{rated } V_R$
C_T Typ. Junction Capacitance (Per Leg)	145	pF	$V_R = 5V_{DC}$ (test signal range 100Khz to 1Mhz) 25°C	
L_S Typical Series Inductance (Per Leg)	5.0	nH	Measured lead to lead 5mm from package body	
dv/dt Max. Voltage Rate of Change	10000	V/μs	(Rated V_R)	

(1) Pulse Width < 300μs, Duty Cycle <2%

Thermal-Mechanical Specifications

Parameters	Value	Units	Conditions	
T_J Max. Junction Temperature Range (*)	-40 to 150	°C		
T_{stg} Max. Storage Temperature Range	-40 to 150	°C		
R_{thJC} Max. Thermal Resistance (Per Leg) Junction to Case (Per Device)	6	°C/W	DC operation * See Fig. 4	
	3			
R_{thJA} Max. Thermal Resistance Junction to Ambient	80	°C/W		
wt Approximate Weight	0.3(0.01)	g(oz.)		
Case Style	D-Pak		Similar to TO-252AA	

(*) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

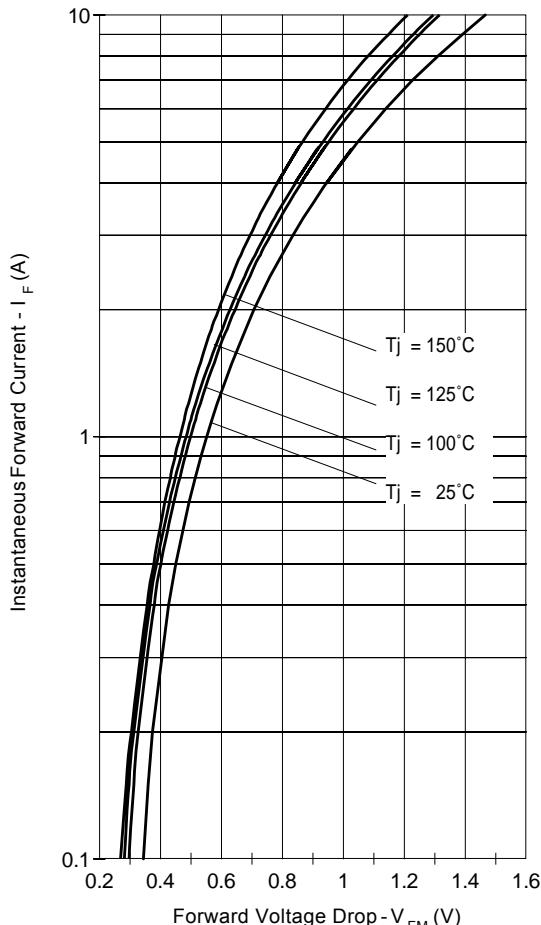


Fig. 1-Max. Forward Voltage Drop Characteristics
 (PerLeg)

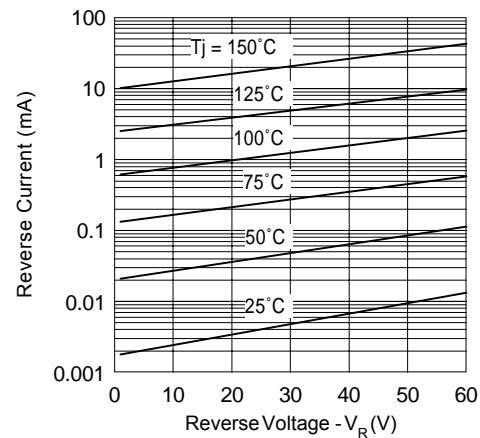


Fig. 2-Typical Values Of Reverse Current
 Vs. Reverse Voltage (PerLeg)

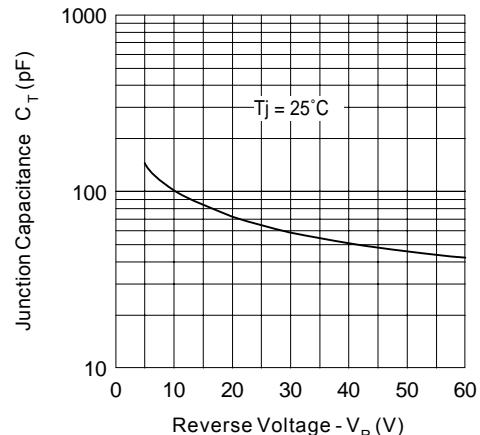


Fig. 3-Typical Junction Capacitance
 Vs. Reverse Voltage (PerLeg)

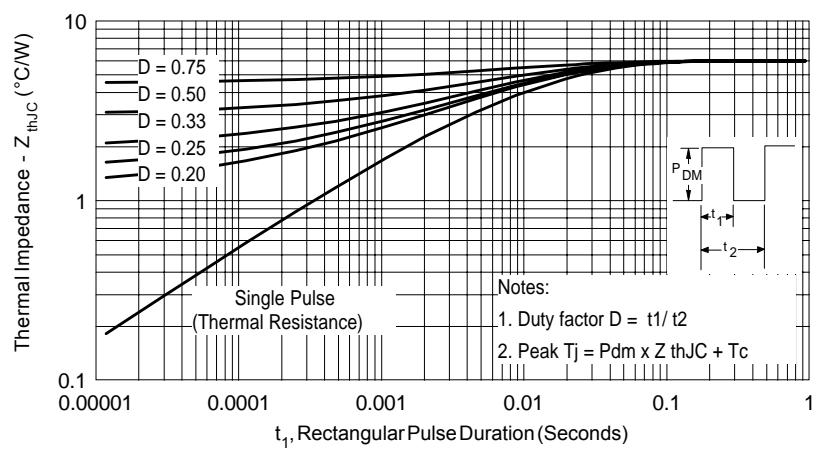


Fig. 4-Max. Thermal Impedance Z_{thJC} Characteristics (PerLeg)

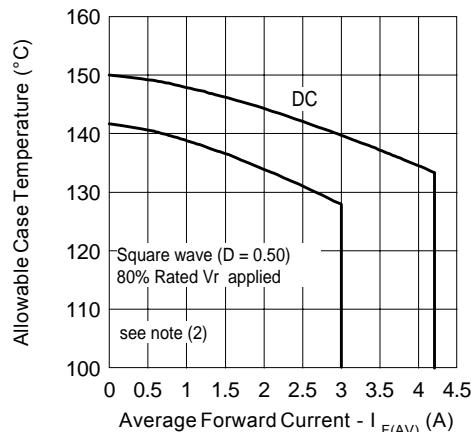


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current (PerLeg)

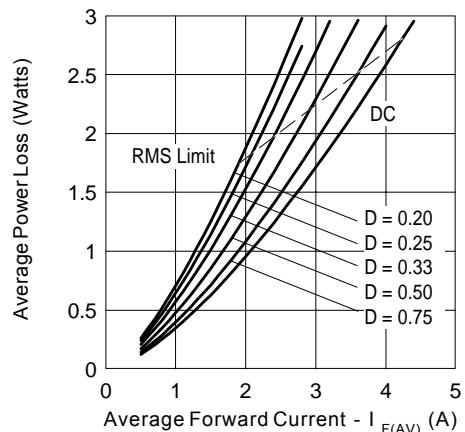


Fig. 6 - Forward Power Loss Characteristics (PerLeg)

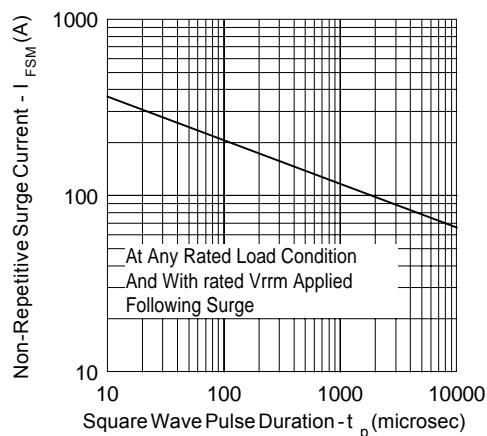
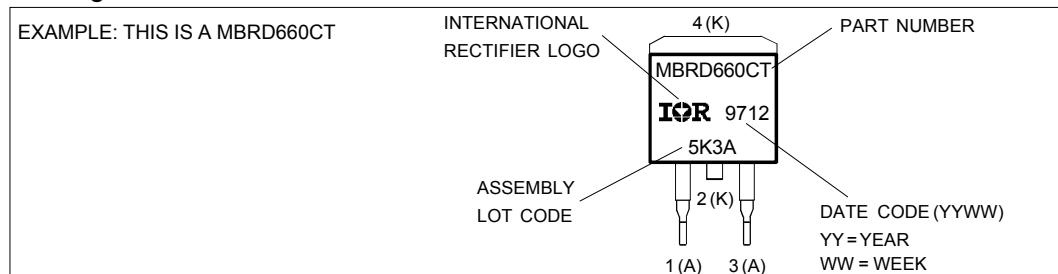


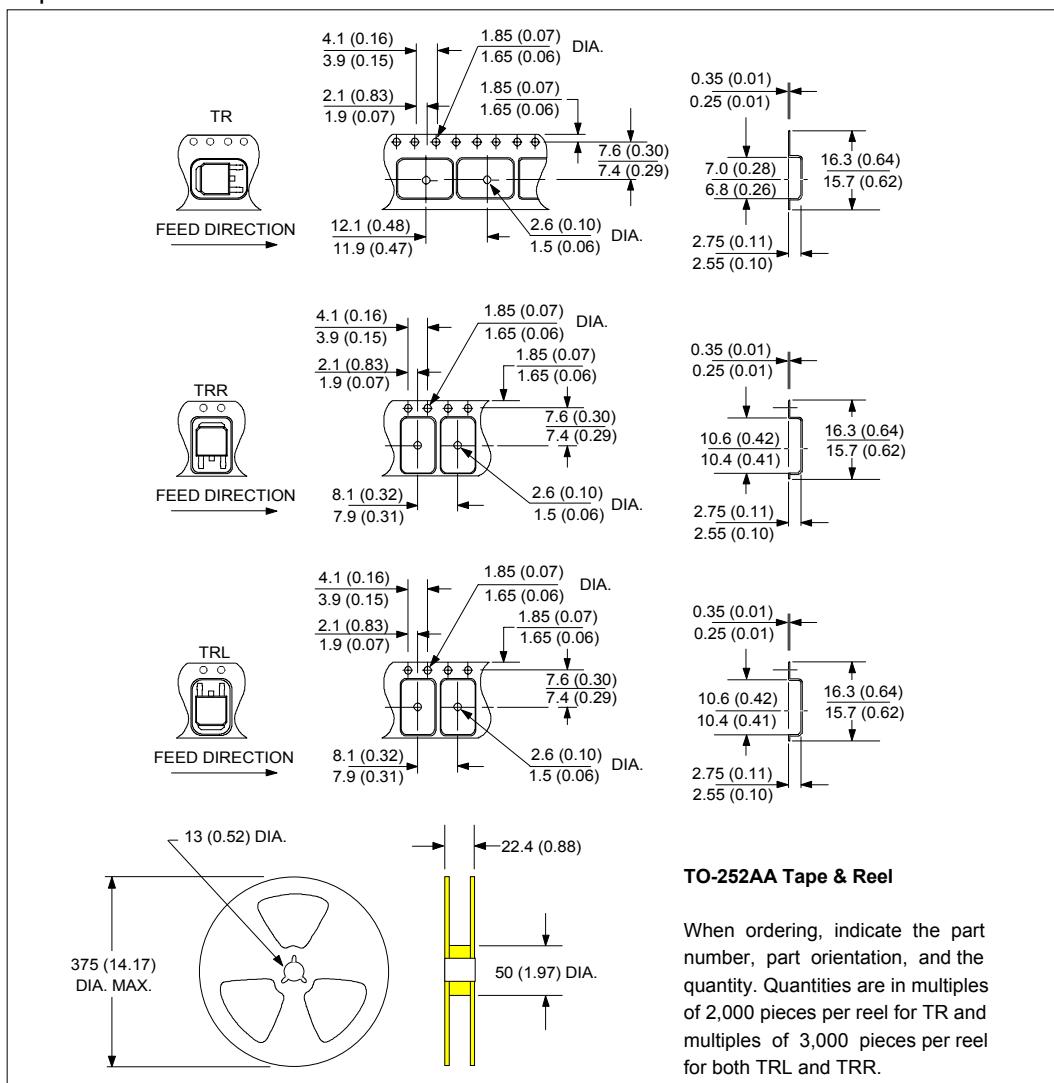
Fig. 7 - Max. Non-Repetitive Surge Current (PerLeg)

(2) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$:
 $P_d = \text{Forward Power Loss} = I_{F(\text{AV})} \times V_{FM} @ (I_{F(\text{AV})}/D)$ (see Fig. 6);
 $P_{d_{REV}} = \text{Inverse Power Loss} = V_{R1} \times I_R (1-D)$; $I_R @ V_{R1} = 80\% \text{ rated } V_R$

Marking Information



Tape & Reel Information



Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

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